NSN 5961-01-029-3435

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View Online at https://aerobasegroup.com/nsn/5961-01-029-3435 **Inclosure Material:** Ceramic or metal **Overall Length:** 2.500 inches **Overall Height:** 0.550 inches **Overall Width:** 1.900 inches **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Mounting Method:** Unthreaded hole Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, dc all semiconductor and 225.0 breakdown voltage, dc all semiconductor and 180.0 reverse voltage, instantaneous all semiconductor **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak all semiconductor and 180.00 amperes source cutoff current universal all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 53711-5169304 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No